R.F. DOUBLE TRIODE

Double triode intended for use as R.F. and A.F. amplifier and self oscillating mixer.

QUICK REFEREN (each un			
Anode current	Ia	10	m A
Transconductance	S	6.1	mA/V
Amplification factor	μ	55	-

HEATING: Indirect by A.C. or D.C.; parallel supply

Heater voltage

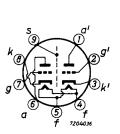
Heater current

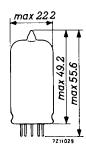
$v_{\mathbf{f}}$	6.3	V
I _f	435	mA

Dimensions in mm

DIMENSIONS AND CONNECTIONS

Base: Noval





ECC85

CAPACITANCES			
Anode to grid	$C_{\mathbf{a}\mathbf{g}}$	1.5	pF
	Ca'g'	1.5	pF
Anode to cathode	Cak	0.17	pF
	Ca'k'	0.18	pF
Anode to cathode + heater + screen	C _{a/kfs}	1.2	pF
	Ca'/k'fs	1.2	pF
Grid to cathode + heater + screen	C _{g/kfs}	3.1	pF
	Cg'/k'fs	3.1	pF
Anode to cathode + heater + screen	$C_{a/kfs}$	1.8	pF
with external screen of 22.5 mm diam.	Ca'/k'fs	1.8	pF
Anode to anode	C _{aa'}	max. 0.04	pF
Grid to grid	Cgg'	max. 0.003	pF
Anode to grid other unit	Cag'	max. 0.008	pF
Grid to anode other unit	Cga'	max. 0.008	pF
Anode to anode with external screen of 22.5 mm diam.	C _{aa'}	max. 0.008	pF
Anode to cathode other unit	Cak'	max. 0.008	pF
Grid to cathode other unit	Cgk'	max. 0.003	pF
Cathode to anode other unit	C _{ka} ,	max. 0.008	pF
Cathode to grid other unit	C _{kg} '	max. 0.003	pF
TYPICAL CHARACTERISTICS			
Anode voltage	v_a	250	V
Grid voltage	v_g	-2.7	V
Anode current	I _a	10	mA
Transconductance	S	6.1	mA/V
Amplification factor	μ	55	-

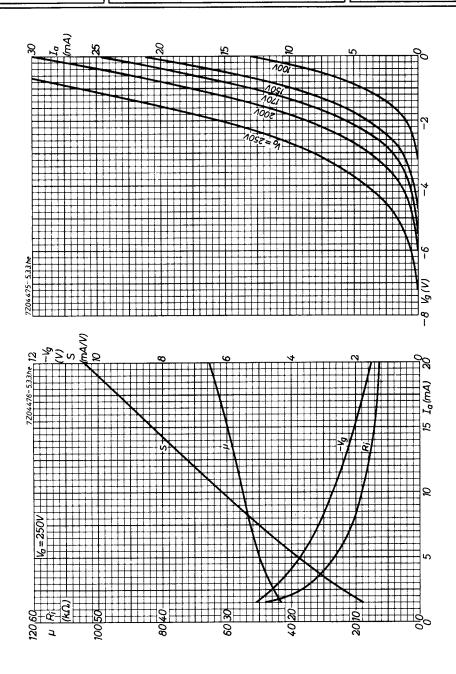
REMARK

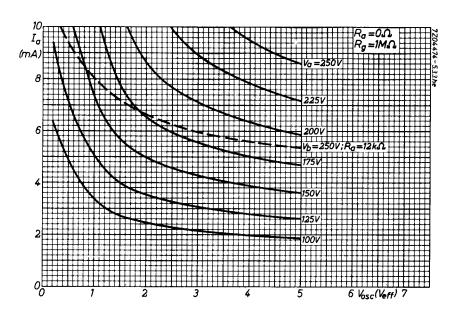
Microphony

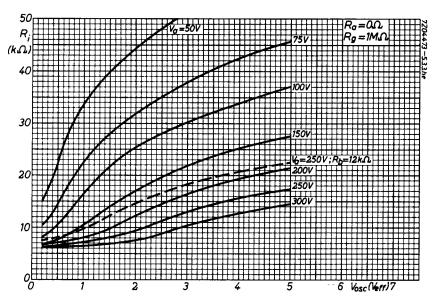
This tube can be used without special precautions against microphony in A.F. applications in which the input voltage $V_i \geq 5~\text{mV}$ for an output of 50 mW (or 50 mV for an output of 5 W) provided the peak acceleration of the tube is not greater than indicated in the section "Microphony" of the "General Operational Recommendations".

OPERATING CHARACTERISTICS

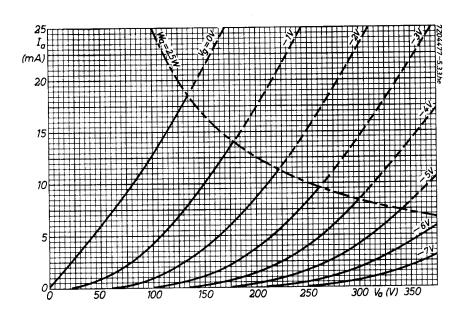
As P. F. amplifier			
As R.F. amplifier Supply voltage	V	250	v
	v_b		V
Anode resistor	Ra	1.8	kΩ
Anode voltage	v_a	230	V
Cathode resistor	R_k	200	Ω
Grid voltage	v_g	-2.2	V
Anode current	Ia	10.8	m A
Transconductance	S	6.8	mA/V
Internal resistance	R_{i}	8.3	kΩ
Grid input resistance (f = 100 MHz)	$r_{\mathbf{g}}$	4.7	kΩ
Equivalent noise resistance	R_{eq}	580	Ω
As self-oscillating mixer			
Supply voltage	v_b	250	v
Anode resistor	R_a	12	$k\Omega$
Grid resistor	$R_{\mathbf{g}}$	1	$M\Omega$
Oscillator voltage	v_{osc}	3.0	v_{RMS}
Anode current	$I_{\mathbf{a}}$	6	mA
Conversion conductance	s_c	3	mA/V
Internal resistance	$R_{\mathbf{i}}$	18	kΩ
Grid input resistance (f = 100 MHz)	$^{\mathrm{r}}g$	15	kΩ
LIMITING VALUES (Design centre rating sy	stem) (Each un	it unless oth	erwise stated)
Anode voltage	v_{a_0}	max. 550	v
	v_a	max. 300	v
Anode dissipation	w_a	max. 2.5	w
Anode dissipation, total for both units	$w_a + w_{a'}$	max. 4.5	w
Cathode current	I _k	max. 15	mA
Grid voltage	$-v_{g}$	max. 100	V
Grid resistor	R _g .	max. 1	$M\Omega$
Cathode to heater voltage	$v_{ m kf}$	max. 90	V

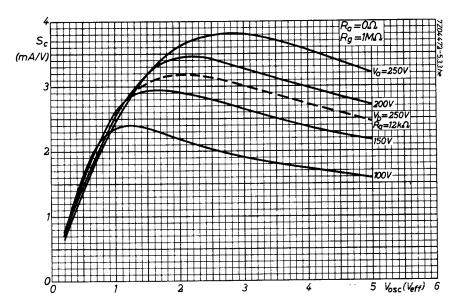




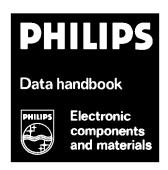


January 1969





6 January 1969



ECC85

page	sheet	date
1	1	1969.12
2	2	1969.01
3	3	1969.01
4	4	1969.01
5	5	1969.01
6	6	1969.01
7	FP	1999.08.14